

HD74HC589

8-bit Serial or Parallel-input/Serial-output Shift Register (with 3-state outputs)

REJ03D0631-0200
(Previous ADE-205-511)
Rev.2.00
Mar 30, 2006

Description

The HD74HC589 is similar in function to the HD74HC597, which is not a 3-state device.

This device consists of an 8-bit storage latch which feeds parallel data to an 8-bit shift register. Data can also be loaded serially (see Function Table). The shift register output, O_H , is a three-state output, allowing this device to be used in bus-oriented systems.






Features

- High Speed Operation: t_{pd} (Shift Clock to Q_H) = 15 ns typ ($C_L = 50$ pF)
- High Output Current: Fanout of 15 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 2$ to 6 V
- Low Input Current: 1 μ A max
- Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max ($T_a = 25^\circ\text{C}$)
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC589FPEL	SOP-16 pin (JEITA)	PRSP0016DH-B (FP-16DAV)	FP	EL (2,000 pcs/reel)
HD74HC589RPEL	SOP-16 pin (JEDEC)	PRSP0016DG-A (FP-16DNV)	RP	EL (2,500 pcs/reel)

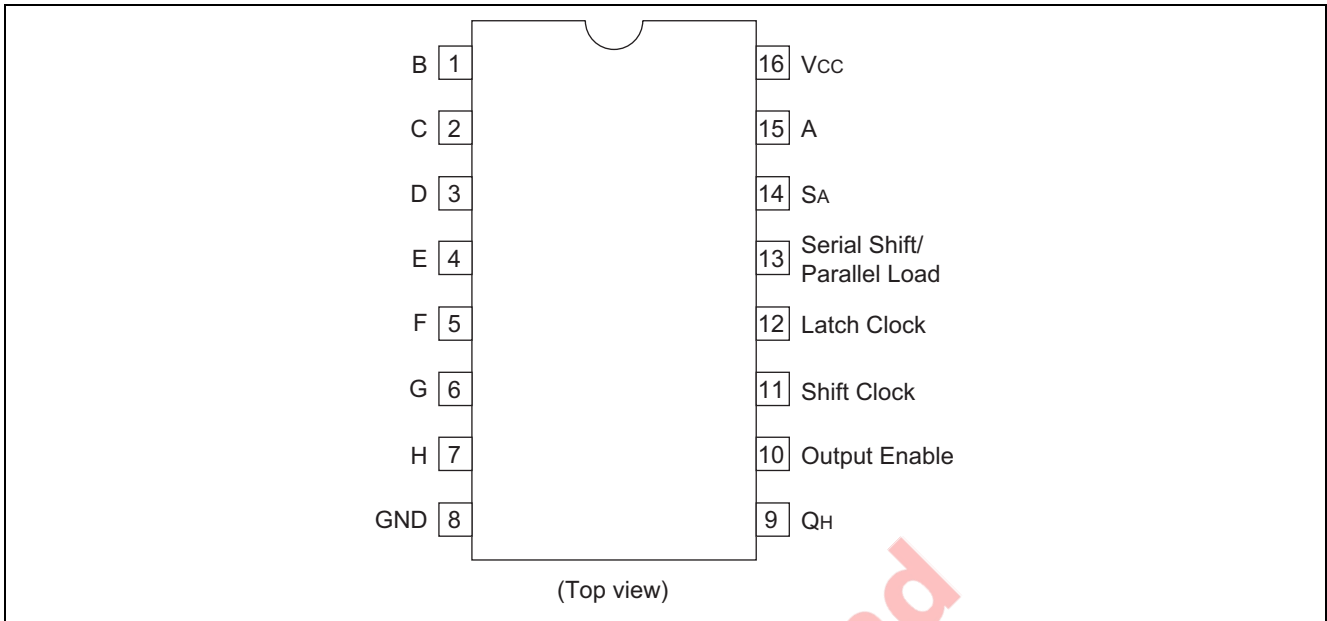
Note: Please consult the sales office for the above package availability.

Function Table

Latch Clock LCK	Shift Clock SCK	Serial Shift/ Parallel Load	Output Enable OE	Function
	X	X	X	Data are loaded into input latches
	X	L	L	Data are loaded from input into shift registers
X	X	L	L	Data are transferred from input latches to shift registers
L, H, 	L, H, 	X	H	Outputs are disabled
X		H	L	Serial shift $Q_n = Q_{n-1}$, $Q_0 = SER$

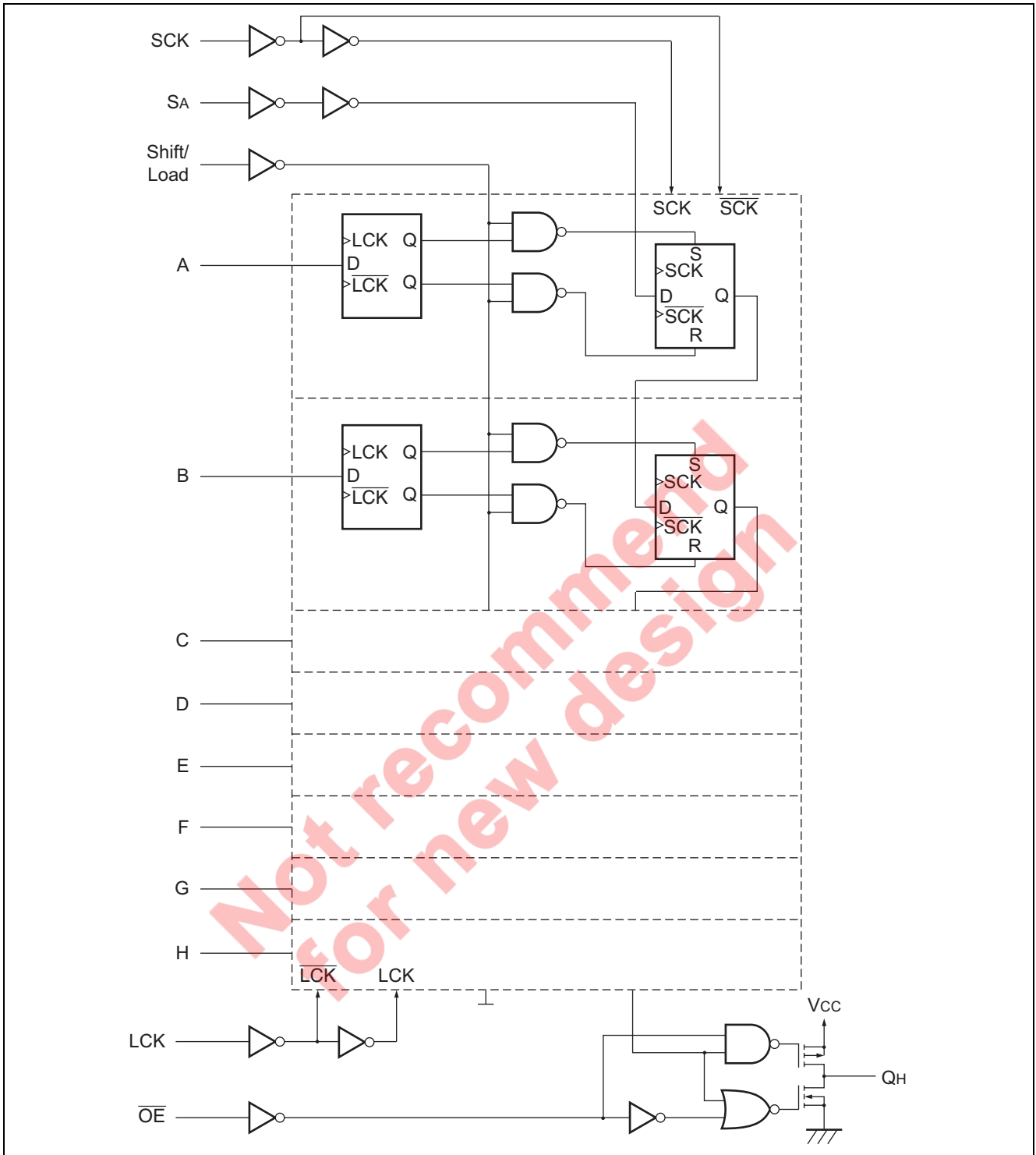
Note: 1. H; High level, L; Low level, X; Irrelevant

Pin Arrangement



Not recommend
for new design

Logic Diagram



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
Input / Output voltage	V_{IN}, V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input / Output diode current	I_{IK}, I_{OK}	± 20	mA
Output current	I_{OUT}	± 35	mA
V_{CC} , GND current	I_{CC} or I_{GND}	± 75	mA
Power dissipation	P_T	500	mW
Storage temperature	T_{stg}	-65 to +150	$^{\circ}C$

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	2 to 6	V	
Input / Output voltage	V_{IN}, V_{OUT}	0 to V_{CC}	V	
Operating temperature	T_a	-40 to 85	$^{\circ}C$	
Input rise / fall time ^{*1}	t_r, t_f	0 to 1000	ns	$V_{CC} = 2.0$ V
		0 to 500		$V_{CC} = 4.5$ V
		0 to 400		$V_{CC} = 6.0$ V

Note: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

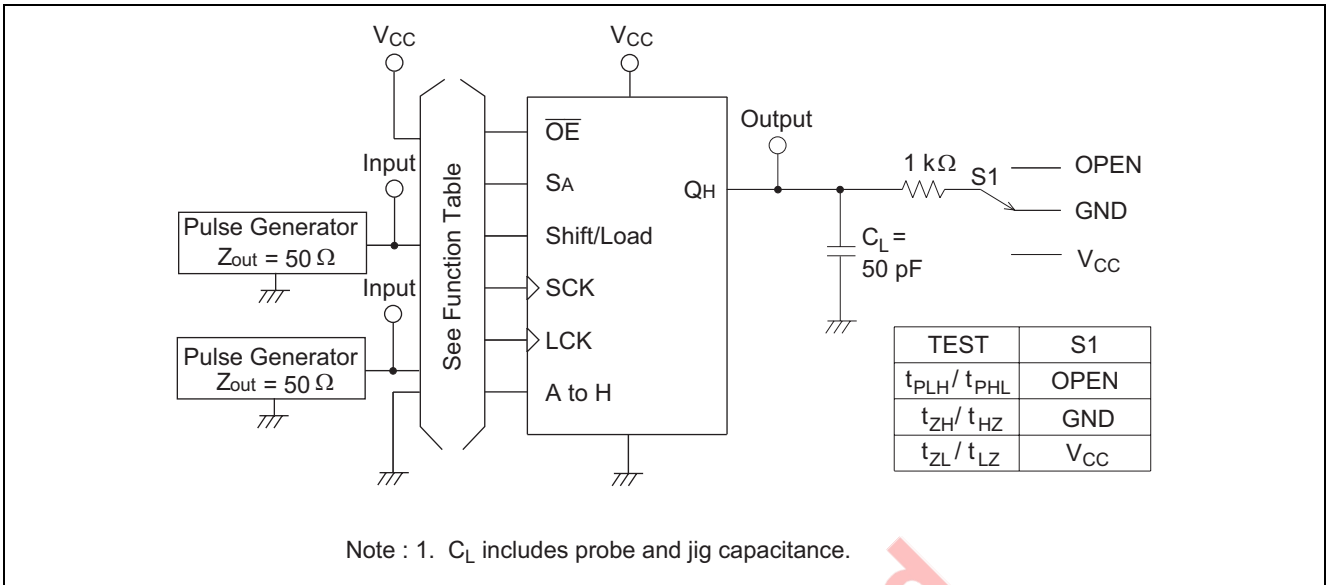
Electrical Characteristics

Item	Symbol	V_{CC} (V)	$T_a = 25^{\circ}C$			$T_a = -40$ to $+85^{\circ}C$		Unit	Test Conditions	
			Min	Typ	Max	Min	Max			
Input voltage	V_{IH}	2.0	1.5	—	—	1.5	—	V		
		4.5	3.15	—	—	3.15	—			
		6.0	4.2	—	—	4.2	—			
	V_{IL}	2.0	—	—	0.5	—	0.5	V		
		4.5	—	—	1.35	—	1.35			
		6.0	—	—	1.8	—	1.8			
Output voltage	V_{OH}	2.0	1.9	2.0	—	1.9	—	V	$V_{in} = V_{IH}$ or V_{IL}	$I_{OH} = -20$ μA
		4.5	4.4	4.5	—	4.4	—			$I_{OH} = -6$ mA
		6.0	5.9	6.0	—	5.9	—			$I_{OH} = -7.8$ mA
		4.5	4.18	—	—	4.13	—			
		6.0	5.68	—	—	5.63	—			
	V_{OL}	2.0	—	0.0	0.1	—	0.1	V	$V_{in} = V_{IH}$ or V_{IL}	$I_{OL} = 20$ μA
		4.5	—	0.0	0.1	—	0.1			
		6.0	—	0.0	0.1	—	0.1			
		4.5	—	—	0.26	—	0.33			$I_{OH} = 6$ mA
		6.0	—	—	0.26	—	0.33			$I_{OH} = 7.8$ mA
Off-state output current	I_{OZ}	6.0	—	—	± 0.5	—	± 5.0	μA	$V_{in} = V_{IH}$ or V_{IL} $V_{out} = V_{CC}$ or GND	
Input current	I_{in}	6.0	—	—	± 0.1	—	± 1.0	μA	$V_{in} = V_{CC}$ or GND	
Quiescent supply current	I_{CC}	6.0	—	—	4.0	—	40	μA	$V_{in} = V_{CC}$ or GND, $I_{out} = 0$ μA	

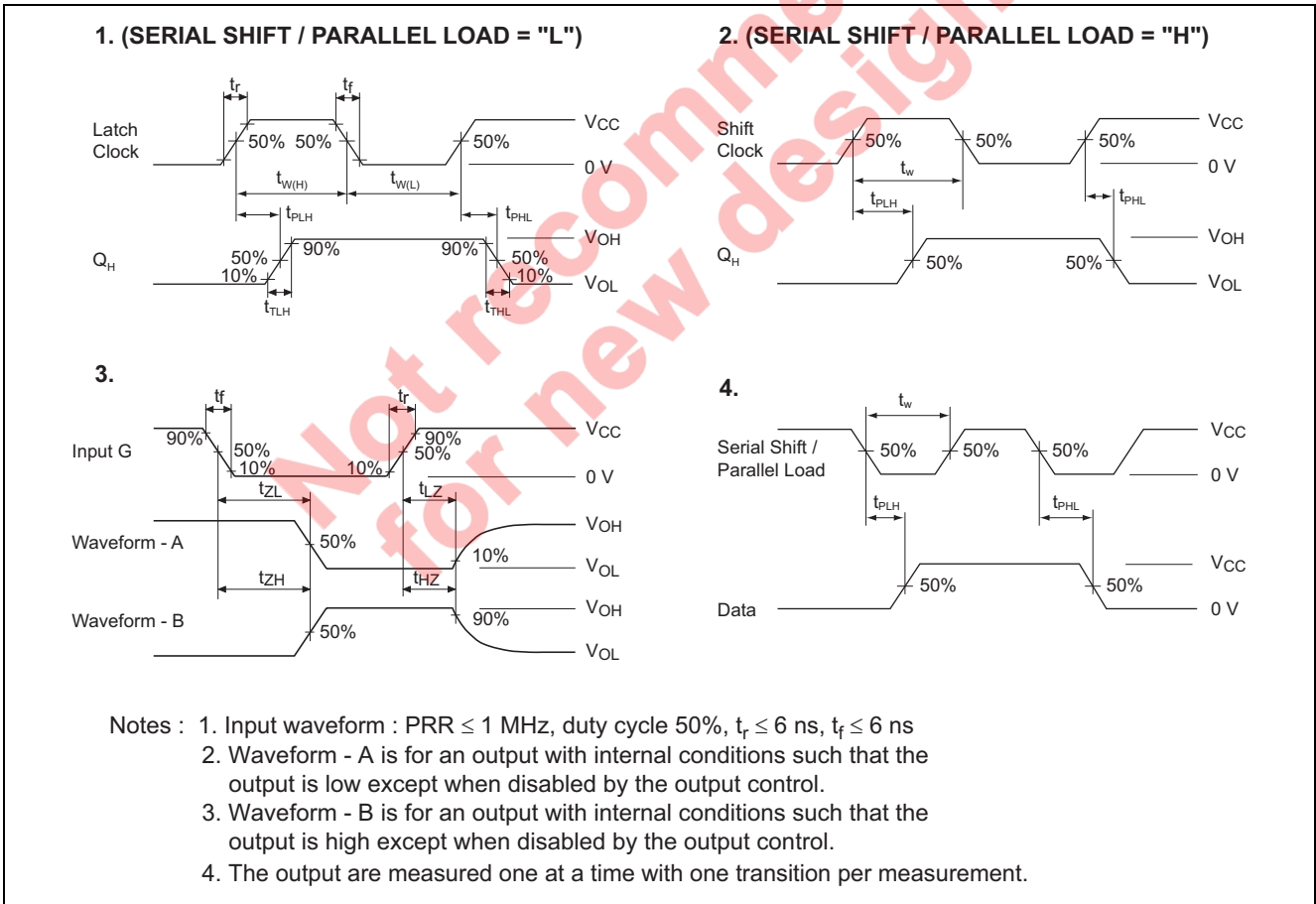
Switching Characteristics ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

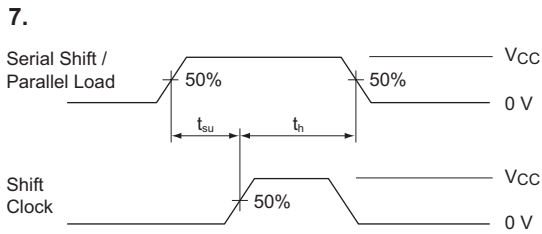
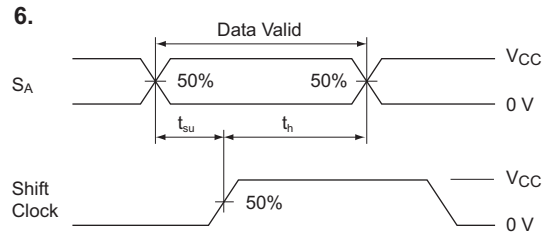
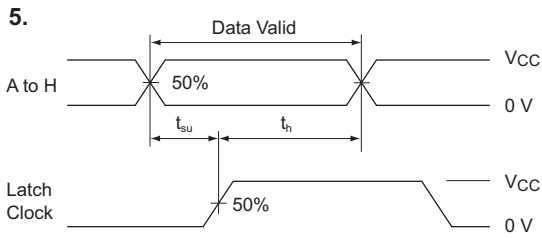
Item	Symbol	V_{CC} (V)	$T_a = 25^\circ\text{C}$			$T_a = -40 \text{ to } +85^\circ\text{C}$		Unit	Test Conditions
			Min	Typ	Max	Min	Max		
Maximum clock frequency	f_{max}	2.0	—	—	5	—	4	MHz	
		4.5	—	—	27	—	21		
		6.0	—	—	32	—	25		
Propagation delay time	t_{PLH}	2.0	—	—	200	—	250	ns	Latch clock to Q_H
		4.5	—	20	40	—	50		
		6.0	—	—	34	—	43		
	t_{PHL}	2.0	—	—	175	—	220	ns	Shift clock to Q_H
		4.5	—	15	35	—	44		
		6.0	—	—	30	—	37		
	t_{PLH}	2.0	—	—	175	—	220	ns	Serial shift/parallel load to Q_H
		4.5	—	16	35	—	44		
		6.0	—	—	30	—	37		
Output enable time	t_{ZL}	2.0	—	—	150	—	190	ns	
		4.5	—	9	30	—	38		
		6.0	—	—	26	—	33		
Output disable time	t_{LZ}	2.0	—	—	150	—	190	ns	
		4.5	—	14	30	—	38		
		6.0	—	—	26	—	33		
Pulse width	t_w	2.0	80	—	—	100	—	ns	
		4.5	16	8	—	20	—		
		6.0	14	—	—	17	—		
Setup time	t_{su}	2.0	100	—	—	125	—	ns	Data to latch clock
		4.5	20	1	—	25	—		
		6.0	17	—	—	21	—		
	t_{su}	2.0	100	—	—	125	—	ns	S_A to shift clock
		4.5	20	—	—	25	—		
		6.0	17	—	—	21	—		
	t_{su}	2.0	100	—	—	125	—	ns	Serial shift/parallel load to shift clock
		4.5	20	—	—	25	—		
		6.0	17	—	—	21	—		
Hold time	t_h	2.0	5	—	—	5	—	ns	Latch clock to data
		4.5	5	0	—	5	—		
		6.0	5	—	—	5	—		
	t_h	2.0	5	—	—	5	—	ns	Shift clock to S_A
		4.5	5	—	—	5	—		
		6.0	5	—	—	5	—		
	t_h	2.0	5	—	—	5	—	ns	Shift clock to serial shift/parallel load
		4.5	5	—	—	5	—		
		6.0	5	—	—	5	—		
Output rise/fall time	t_{TLH}	2.0	—	—	75	—	95	ns	
		4.5	—	5	15	—	19		
		6.0	—	—	13	—	16		
Input capacitance	C_{in}	—	—	5	10	—	10	pF	

Test Circuit



Waveforms

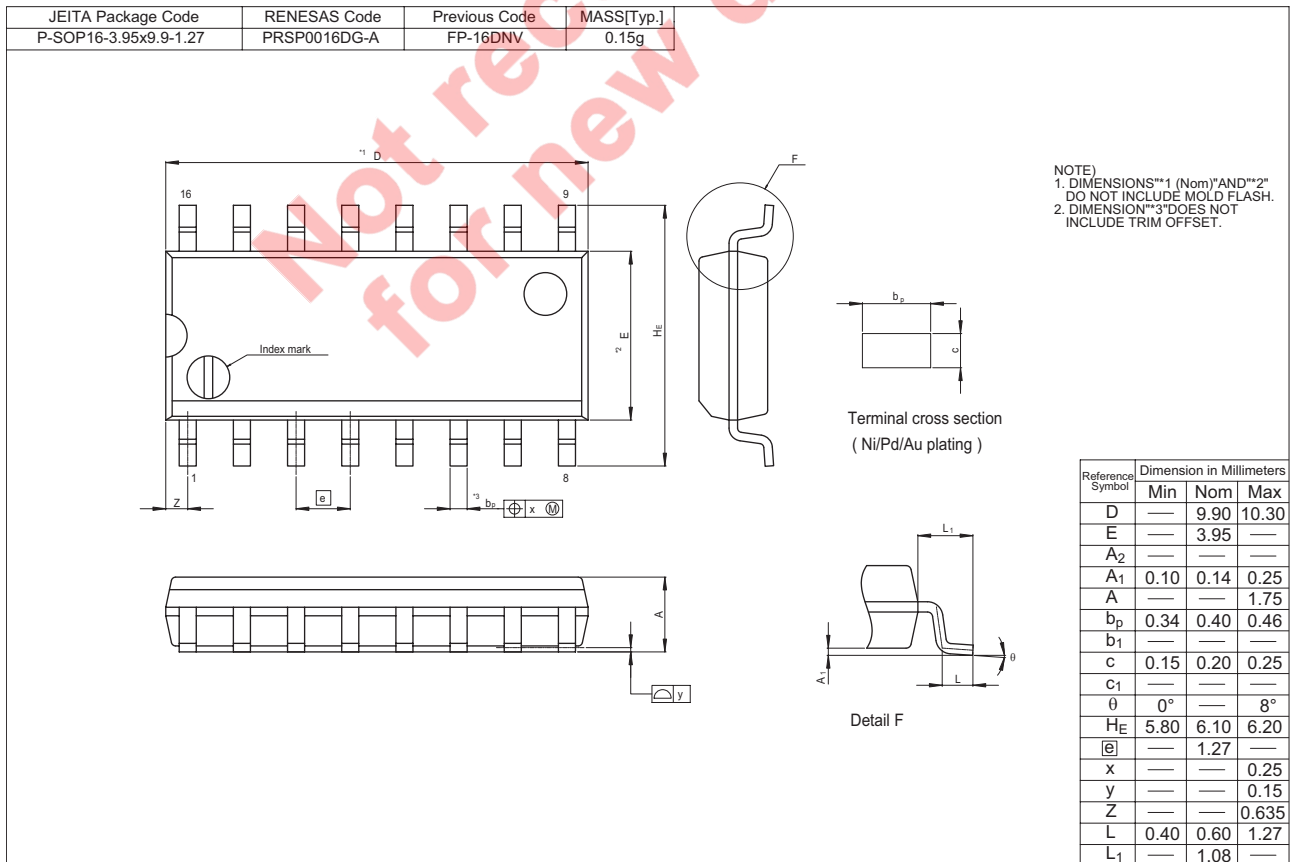
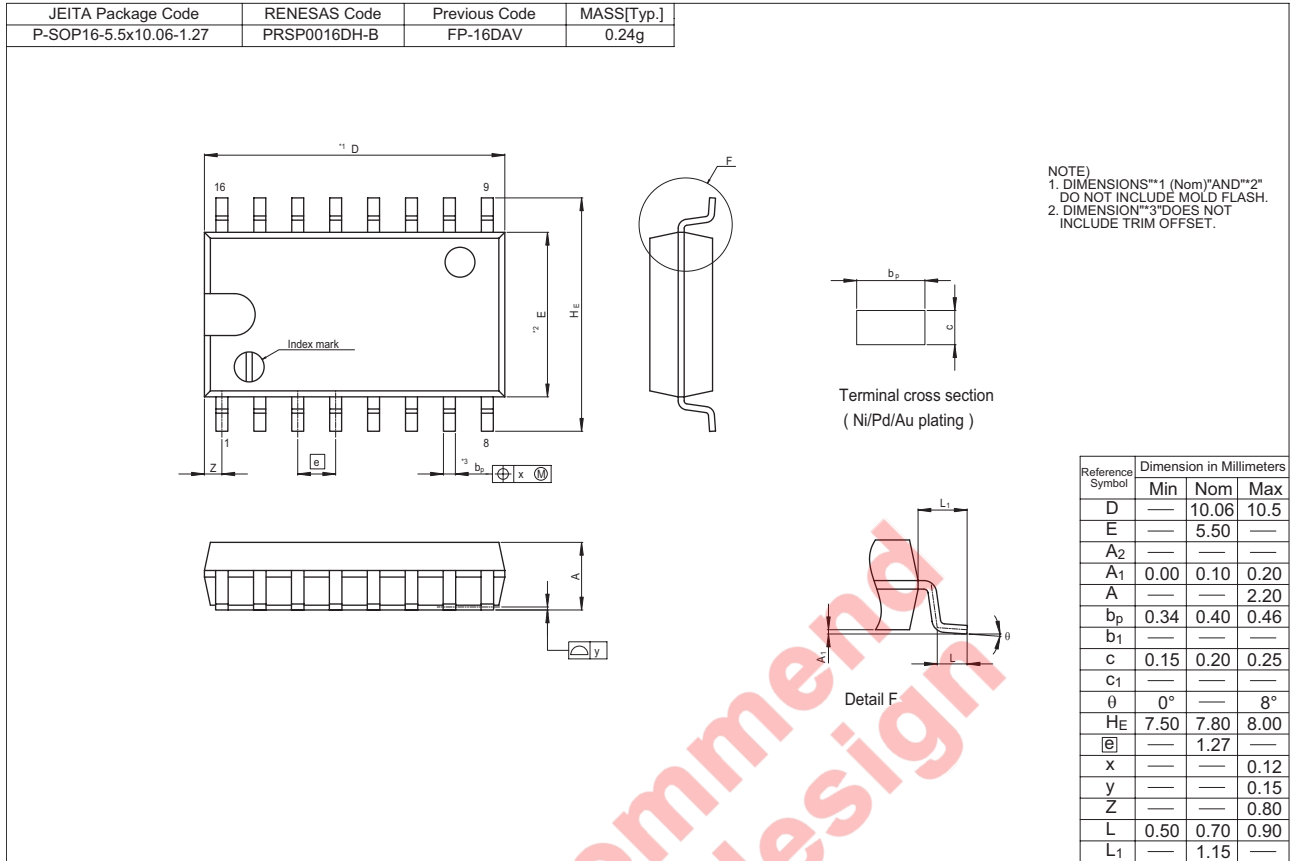




- Notes : 1. Input waveform : PRR \leq 1 MHz, duty cycle 50%, $t_r \leq$ 6 ns, $t_f \leq$ 6 ns
 2. The output are measured one at a time with one transition per measurement.

Not recommended
for new design

Package Dimensions



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